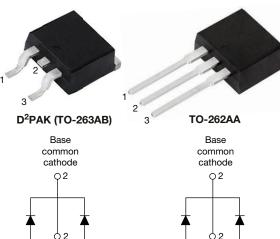
www.vishay.com

VS-40CTQ150SHM3, VS-40CTQ150-1HM3

Vishay Semiconductors

High Performance Schottky Rectifier, 2 x 20 A



Common 👌 3 10 Common 0 3 Anode cathode Anode Anode cathode Anode

VS-40CTQ150SHM3

10

VS-40CTQ150-1HM3

| PRIMARY CHARACTERISTICS | | | | |
|----------------------------------|---|--|--|--|
| I _{F(AV)} | 2 x 20 A | | | |
| V _R | 150 V | | | |
| V _F at I _F | 0.71 V | | | |
| I _{RM} | 15 mA at 125 °C | | | |
| T _J max. | 175 °C | | | |
| E _{AS} | 1 mJ | | | |
| Package | D ² PAK (TO-263AB), TO-262AA | | | |
| Circuit configuration | Common cathode | | | |

FEATURES

- Very low forward voltage drop
- 175 °C T_J operation
- Center tap TO-220 package
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · Guard ring for enhanced ruggedness and long term reliability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C
- Meet JESD 201 class 1 whisker test
- AEC-Q101 gualified
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

The VS-40CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

| MAJOR RATINGS AND CHARACTERISTICS | | | | | | | |
|-----------------------------------|---|-------------|-------|--|--|--|--|
| SYMBOL | CHARACTERISTICS | VALUES | UNITS | | | | |
| I _{F(AV)} | Rectangular waveform | 40 | A | | | | |
| V _{RRM} | | 150 | V | | | | |
| I _{FSM} | t _p = 5 μs sine | 1500 | А | | | | |
| V _F | $20 \text{ A}_{\text{pk}}, \text{ T}_{\text{J}} = 125 \text{ °C} \text{ (per leg)}$ | 0.71 | V | | | | |
| TJ | | -55 to +175 | °C | | | | |

| VOLTAGE RATINGS | | | | | | |
|--------------------------------------|-------------------------------------|-------|---|--|--|--|
| PARAMETER | VS-40CTQ150SHM3 VS-40CTQ150-1HM3 | UNITS | | | | |
| Maximum DC reverse voltage | V _R | 150 | V | | | |
| Maximum working peak reverse voltage | V _{RWM} | 150 | v | | | |

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COMPLIANT HALOGEN FREE



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| ABSOLUTE MAXIMUM RATINGS | | | | | | | | |
|---|--------------------|--|---|------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST COND | TEST CONDITIONS | | UNITS | | | |
| Maximum average forward per leg | Iran | 50 % duty cycle at Ta – 140 ° | 50 % duty cycle at T_{C} = 140 °C, rectangular waveform | | | | | |
| current, see fig. 5 per device | I _{F(AV)} | | 40 | | | | | |
| | | 5 µs sine or 3 µs rect. pulse | Following any rated load condition and | 1500 | A | | | |
| Maximum peak one cycle non-repetitive surge current per leg, see fig. 7 | I _{FSM} | 10 ms sine or 6 ms rect. pulse | with rated V _{RRM} | 250 | | | | |
| Non-repetitive avalanche energy per leg | E _{AS} | T _J = 25 °C, I _{AS} = 1.5 A, L = 0.9 mH | | 1.0 | mJ | | | |
| Repetitive avalanche current per leg | I _{AR} | Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical | | 1.5 | А | | | |

| ELECTRICAL SPECIFICATIONS | | | | | | | | | |
|--|--------------------------------|--|---------------------------------------|--------|-------|--|--|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | VALUES | UNITS | | | | |
| Maximum forward voltage drop per leg See fig. 1 | | 20 A | T 05 %C | 0.93 | | | | | |
| | V (1) | 40 A | T _J = 25 °C | 1.16 | v | | | | |
| | V _{FM} ⁽¹⁾ | 20 A | | 0.71 | | | | | |
| | | 40 A | T _J = 125 °C | 0.85 | | | | | |
| Maximum reverse leakage current per leg | . (1) | T _J = 25 °C | | 50 | μA | | | | |
| See fig. 2 | I _{RM} ⁽¹⁾ | T _J = 125 °C | V _R = Rated V _R | 15 | mA | | | | |
| Maximum junction capacitance per leg | CT | $V_{R} = 5 V_{DC}$ (test signal range | ge 100 kHz to 1 MHz), 25 °C | 450 | pF | | | | |
| Typical series inductance per leg | L _S | Measured lead to lead 5 mm from package body | | 8.0 | nH | | | | |
| Maximum voltage rate of change | dV/dt | Rated V _R | 10 000 | V/µs | | | | | |

Note

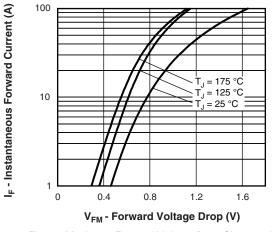
⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

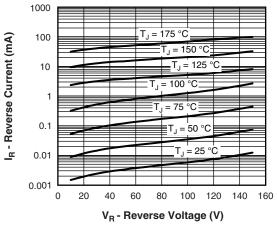
| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|---|-----------------------------------|--|-------------|--------|--|--|--|--|
| PARAMETER SYMBOL TEST CO | | TEST CONDITIONS | VALUES | UNITS | | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -55 to +175 | °C | | | | |
| Maximum thermal resistance, junction to case per leg | P | DC operation See fig. 4 | 1.5 | | | | | |
| Maximum thermal resistance, junction to case per package | – R _{thJC} | DC operation | 0.75 | °C/W | | | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, smooth and greased | 0.5 | | | | | |
| Approvimeto weight | | | 2 | g | | | | |
| Approximate weight | | | 0.07 | oz. | | | | |
| Marking daviag | | Case style D ² PAK (TO-263AB) | 40CTQ | 150SH | | | | |
| Marking device | | Case style TO-262 | 40CTQ | 150-1H | | | | |

VS-40CTQ150SHM3, VS-40CTQ150-1HM3









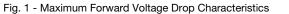


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

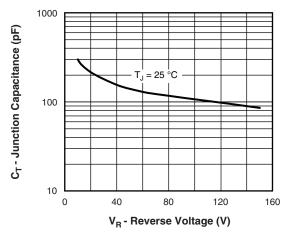


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

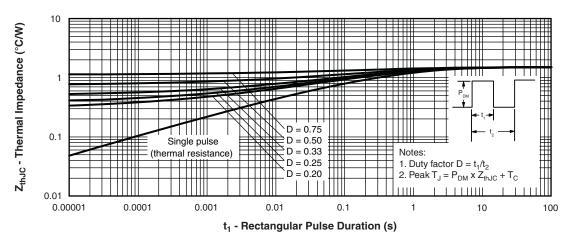


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

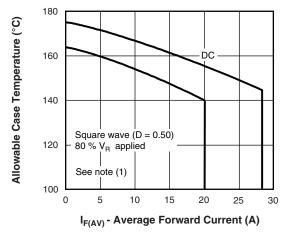
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 Document Number: 96382

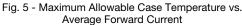
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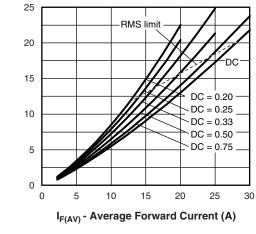


VS-40CTQ150SHM3, VS-40CTQ150-1HM3

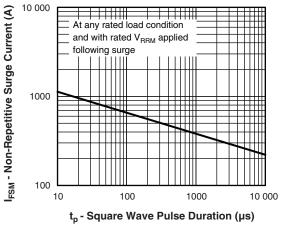
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Average Power Loss (W)

Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} - \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{V}_{\mathsf{R}} \ \mathsf{applied} \end{array}$



VS-40CTQ150SHM3, VS-40CTQ150-1HM3

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ORDERING INFORMATION TABLE

| VS- | 40 | С | т | Q | 150 | S | TRL | н | М3 |
|----------|-------------------------|---|---|--|---|--|---|---|---|
| 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 10 |
|] - | Visł | nay Sem | niconduc | ctors pro | oduct | | | | |
| - 1 | - Current rating (40 A) | | | | | | | | |
| - 1 | Circ | Circuit configuration: | | | | | | | |
| | C = | C = common cathode | | | | | | | |
| - [| T = | TO-220 | | | | | | | |
| - 1 | Sch | ottky "C | " series | | | | | | |
| - 13 | Volt | age rati | ng (150 | = 150 \ | /) | | | | |
| - [| • S | = D ² PA | K | | | | | | |
| | • -1 | = TO-2 | 62 | | | | | | |
| - 1 | • N | one = tu | be (50 p | pieces) | | | | | |
| _ | • TI | | | | | | | | |
| | • TI | | | | | | | | |
| - 1 | | | | | | | | | |
| <u> </u> | | | • | | complia | nt, and | termina | ition lea | ld (Pb)-fi |
| | | 1 2 1 2 - Vist - Cur - Circ C = - T = - Sch - Volt - Sch - 1 - Nu - TI - TI - H = | 1 2 3 1 2 3 1 2 3 1 2 3 1 - Vishay Sem - Current rati - Circuit conf C = commo - T = TO-220 - Schottky "G - Voltage rati - Schottky "G - Voltage rati - S = D ² PA - None = tu • TRL = tap • TRR = tap • H = AEC-Q | 1 2 3 4 1 2 3 4 1 2 3 4 1 2 3 4 1 2 3 4 1 2 3 4 1 2 3 4 1 2 3 4 1 - Current rating (40 A) - Circuit configuration C C common cathod - - T = TO-220 - Schottky "Q" series - - Voltage rating (150 - S = D ² PAK - -1 = TO-262 - None = tube (50 p) - TRL = tape and registric - TRR = tape and registric - H = AEC-Q101 qual | 1 2 3 4 5 - Vishay Semiconductors productors productors - Current rating (40 A) - Circuit configuration: C C - Circuit configuration: C C - T = TO-220 - Schottky "Q" series - Voltage rating (150 = 150 N) - - - S = D ² PAK - - - None = tube (50 pieces) - TRL = tape and reel (left - TRR = tape and reel (right) - H = AEC-Q101 qualified | 1 2 3 4 5 6 - Vishay Semiconductors product - Current rating (40 A) - Circuit configuration: C = common cathode - T = TO-220 - Schottky "Q" series - Voltage rating (150 = 150 V) - S = D ² PAK • -1 = TO-262 - None = tube (50 pieces) • TRL = tape and reel (left oriented • TRR = tape and reel (right orient - H = AEC-Q101 qualified | 1 2 3 4 5 6 7 - Vishay Semiconductors product - Current rating (40 A) - Circuit configuration: C = common cathode - T = TO-220 - Schottky "Q" series - Voltage rating (150 = 150 V) - S = D ² PAK -1 = TO-262 - None = tube (50 pieces) - TRL = tape and reel (left oriented - for D - TRR = tape and reel (right oriented - for D - H = AEC-Q101 qualified | 1 2 3 4 5 6 7 8 - Vishay Semiconductors product - Current rating (40 A) - Circuit configuration: C = common cathode - T = TO-220 - Schottky "Q" series - Voltage rating (150 = 150 V) - S = D ² PAK -1 = TO-262 - None = tube (50 pieces) - TRL = tape and reel (left oriented - for D ² PAK o - TRR = tape and reel (right oriented - for D ² PAK - H = AEC-Q101 qualified | 1 2 3 4 5 6 7 8 9 - Vishay Semiconductors product - Current rating (40 A) - Circuit configuration: C = common cathode - T = TO-220 - Schottky "Q" series - Voltage rating (150 = 150 V) - S = D ² PAK -1 = TO-262 - None = tube (50 pieces) - TRL = tape and reel (left oriented - for D ² PAK only) - TRR = tape and reel (right oriented - for D ² PAK only) - H = AEC-Q101 qualified |

| ORDERING INFORMATION (Example) | | | | | | | | |
|--------------------------------|------------------|------------------------|--------------------------|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | |
| VS-40CTQ150SHM3 | 50 | 1000 | Antistatic plastic tubes | | | | | |
| VS-40CTQ150STRLHM3 | 800 | 800 | 13" diameter reel | | | | | |
| VS-40CTQ150STRRHM3 | 800 | 800 | 13" diameter reel | | | | | |
| VS-40CTQ150-1HM3 | 50 | 1000 | Antistatic plastic tubes | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | |
|----------------------------|-------------------------------|--------------------------|--|--|--|
| Dimensions | D ² PAK (TO-263AB) | www.vishay.com/doc?96164 | | | |
| Dimensions | TO-262AA | www.vishay.com/doc?96165 | | | |
| | D ² PAK (TO-263AB) | www.vishay.com/doc?95444 | | | |
| Part marking information | TO-262AA | www.vishay.com/doc?95443 | | | |
| Packaging information | | www.vishay.com/doc?95032 | | | |
| SPICE model | | www.vishay.com/doc?95434 | | | |

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Vishay Semiconductors

D²PAK

DIMENSIONS in millimeters and inches



| ota | ted | 90 | °C |
|----------|------|-------------|----|
| <u>S</u> | cale | <u>ə:</u> 8 | :1 |

| SYMBOL | MILLIM | ETERS | INC | HES | NOTES | |
|--------|--------|-------|-------|-------|-------|--|
| STMBOL | MIN. | MAX. | MIN. | MAX. | NOTES | |
| A | 4.06 | 4.83 | 0.160 | 0.190 | | |
| A1 | 0.00 | 0.254 | 0.000 | 0.010 | | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 | |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | |
| с | 0.38 | 0.74 | 0.015 | 0.029 | | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 | |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 | |

| SYMBOL | MILLIM | ETERS | INC | NOTES | |
|--------|----------|-------|-----------|-------|-------|
| STNDUL | MIN. | MAX. | MIN. | MAX. | NOTES |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.100 BSC | | |
| Н | 14.61 | 15.88 | 0.575 | 0.625 | |
| L | 1.78 | 2.79 | 0.070 | 0.110 | |
| L1 | - | 1.65 | - | 0.066 | 3 |
| L2 | 1.27 | 1.78 | 0.050 | 0.070 | |
| L3 | 0.25 BSC | | 0.010 | BSC | |
| L4 | 4.78 | 5.28 | 0.188 | 0.208 | |

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

(3) Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

(5) Datum A and B to be determined at datum plane H

(6) Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

Revision: 13-Jul-17

1

Document Number: 96164

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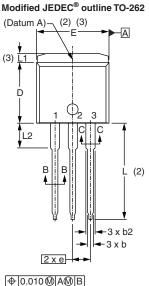
Outline Dimensions

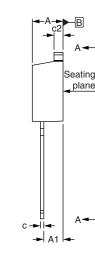


Vishay Semiconductors

TO-262AA

DIMENSIONS in millimeters and inches





F D1 (3) (3) Section A - A Base (4) Plating b1. b3 metal ≰ c1 (4) -(b, b2)-Section B - B and C - C Scale: None





Diodes 1. - Anode (two die)/open (one die) 2., 4. - Cathode 3. - Anode

Lead assignments

| SYMBOL | MILLIMETERS | | INCHES | | NOTEO |
|--------|-------------|-------|-----------|-------|-------|
| | MIN. | MAX. | MIN. | MAX. | NOTES |
| А | 4.06 | 4.83 | 0.160 | 0.190 | |
| A1 | 2.03 | 3.02 | 0.080 | 0.119 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 | |
| b1 | 0.51 | 0.89 | 0.020 | 0.035 | 4 |
| b2 | 1.14 | 1.78 | 0.045 | 0.070 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 |
| С | 0.38 | 0.74 | 0.015 | 0.029 | |
| c1 | 0.38 | 0.58 | 0.015 | 0.023 | 4 |
| c2 | 1.14 | 1.65 | 0.045 | 0.065 | |
| D | 8.51 | 9.65 | 0.335 | 0.380 | 2 |
| D1 | 6.86 | 8.00 | 0.270 | 0.315 | 3 |
| E | 9.65 | 10.67 | 0.380 | 0.420 | 2, 3 |
| E1 | 7.90 | 8.80 | 0.311 | 0.346 | 3 |
| е | 2.54 BSC | | 0.100 BSC | | |
| L | 13.46 | 14.10 | 0.530 | 0.555 | |
| L1 | - | 1.65 | - | 0.065 | 3 |
| L2 | 3.56 | 3.71 | 0.140 | 0.146 | |

 ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
 ⁽²⁾ Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the second dimensioner of the second dimensis of the second dimensioner of the second dimensioner of the the outmost extremes of the plastic body (3)

Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only (5)

Controlling dimension: inches

(6) Outline conform to JEDEC® TO-262 except A1 (max.), b (min., max.), b1 (min.), b2 (max.), c (min.), c1(min.), c2 (max.), D (min.), E (max.), L1 (max.), L2 (min., max.)

Revision: 30-Nov-17

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